

Specification Sheet

DSP Silicon Wafer P Type

(12", Boron Doped)

Stock No: NS6130-10-1264, CAS: N/A

Product	:	Silicon Wafer 12"
Stock No	:	NS6130-10-1264
CAS	:	7440-21-3
Diameter	:	12"
Thickness	:	775±25µm
Type	:	P
Resistivity	:	1~30Ω.cm
TTV	:	≤ 2µm
STIR	:	≤ 5µm
GLOBAL TIR	:	≤ 40 µm
Front Surface	:	Polished
Back Surface	:	Polished
Main Inspect Verifier	:	Manager QC

Note: Product Specification are subject to amendment and may change over time

Characterization of DSP Silicon Wafer P Type



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